PRELIMINARY DATA SHEET 53253 **RADIATION TOLERANT, 90V - 0.8A** HYBRID MICROELECTRONICS DUAL POWER MOSFET OPTOCOUPLERS **PRODUCTS DIVISION** Features: Applications: Designed for 100 krad(Si) Total Dose Satellite/Space systems • • 8-Pin Dual-In-Line Hermetic Package Military/High Reliability Systems • Performance over -55°C to +125°C Standard 28 VDC and 48 VDC Load Driver • . **Compact Isolation Solid State Switches** Aircraft Controls . • Continuous Output Current: 0.8 A⁽¹⁾ Electromechanical and Solid State Relay • Optically Coupled between Input and Output Replacement . Isolation Tested to 1000 VDC I/O Modules • . Switching Heaters High Level of Transient Immunity • 3 A Output Surge Current • Shock and Vibration Resistant MIL-PRF-38534 screening optional

DESCRIPTION

The 53253 is two power MOSFET optocouplers in a single 8-pin dual-in-line package suitable for applications where two independent switches and radiation tolerant performance are required. The popular hermetic eight-pin dual-in-line ceramic package combined with 1000 VDC isolation between input and output and between two isolated relays, makes this device ideal for solid-state relay applications. Performance is specified over the full military temperature range. This device is available as COTS, or screened to MIL-PRF-38534, Table C-IX, Class H or custom screening. Lead options support both through-hole and surface-mount assembly. Gold plated leads are standard, but other lead finishes per MIL-PRF-38534 are also available.

Functionally, the device operates as two SPST, normally open (2 Form A) solid-state relays. Each relay is actuated by an input current, which can be driven from a standard TTL device. The input current biases a light emitting diode that is optically coupled to an integrated photovoltaic diode array. The photovoltaic diode array energizes control circuitry that operates the output MOSFET.

ABSOLUTE MAXIMUM RATINGS:

(Per relay unless otherwise noted)

Storage Temperature Range Operating Ambient Temperature - T_A Junction Temperature - T_J	
Lead Solder Temperature for 10 seconds	
	(1.6 mm below seating plane)
Average Input Current - I _F	
Peak Repetitive Input Current - I _{Fpk}	
	(pulse width < 100 ms; duty cycle < 50%)
Peak Surge Input Current - I _{Fpk} surge	100 mA
	(pulse width < 0.2 ms ; duty cycle < 0.1%)
Continuous Output Current per relay - Io	
Single Shot Output Current per relay- I_{Opk} surge (pulse width < 10 ms) Output Voltage - V_{O}	

RECOMMENDED OPERATING CONDITIONS:

Parameter	Symbol	Min.	Max.	Units
Input Current (ON)	I _{F (ON)}	5	20	mA
Input Voltage (OFF)	$V_{F(OFF)}$	0	0.6	VDC
Operating Temperature	T _A	-55	+125	°C

ELECTRICAL SPECIFICATIONS (Pre-Irradiation)

 $T_A = -55^{\circ}C$ to +125°C, unless otherwise specified.

Parameter	Symbol	Min.	Тур.*	Max.	Unit s	Test Conditions	Notes
Output Withstand Voltage	$V_{O(OFF)}$	90			V	V _F = 0.6 V I _O = 10 μA	
Output On-Resistance	R _(ON)		0.6	1.2	Ω	$I_{F} = 10 \text{ mA}$ $I_{O} = 0.8 \text{ A}$ (pulse duration $\leq 30 \text{ ms}$)	2
Output Leakage Current	I _{O (OFF)}			10	μA	V _F = 0.6 V V _O = 90 V	
Input Forward Voltage	V _F	1.0	1.6	2.1	V	I _F = 10 mA	
Input Reverse Breakdown Voltage	V _R	5			V	I _F = 10 μA	
Input-Output Isolation	I_{I-O}			1	μA	$\label{eq:RH} \begin{array}{l} RH \leq 45\%, t = 5 \; s \\ V_{\text{I-O}} = 1000 \; \text{VDC} \\ T_{\text{A}} = 25^{\circ}\text{C} \end{array}$	3
Channel-channel Isolation	I _{ISO}			1	μA	$\label{eq:RH} \begin{array}{l} {\sf RH} \le 45\%, t=5 \; s \\ {\sf V}_{\rm ISO} = 1000 \; {\sf VDC} \\ {\sf T}_{\sf A} = 25^{\circ}{\rm C} \end{array}$	3
Turn-On Time	t _{on}			6	ms	I _F = 10 mA V _O = 28 V I _O = 0.8 A	
Turn-Off time	t _{OFF}			2	ms	I _F = 10 mA V _O = 28 V I _O = 0.8 A	

* All typical values are at $T_A = 25^{\circ}$ C, $I_{F(ON)} = 10$ mA, $V_{F(OFF)} = 0.6$ V unless otherwise specified.

Notes:

- 1. Maximum average current rating where the case temperature (T_c) is maintained below 120°C.
- 2. During the pulsed R_{ON} measurement (I_O duration < 30 ms), ambient (T_A) and case temperature (T_C) are equal.
- 3. This is a momentary withstand test, not a continuous operating condition.
- 4. Typical junction to case thermal resistance (θ_{JC}) for the device is 15°C/W, where case temperature (T_c) is measured at the center of the package bottom.

CAUTION:

Care should be taken not to exceed the maximum output power dissipation, maximum case temperature, and maximum junction temperature when repetitively switching loads.

Terminal number	Terminal Symbol
1	+IN 1
2	- IN 1
3	- OUT 2
4	+OUT 2
5	+IN 2
6	- IN 2
7	- OUT 1
8	+OUT 1

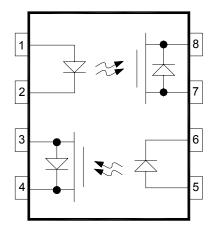
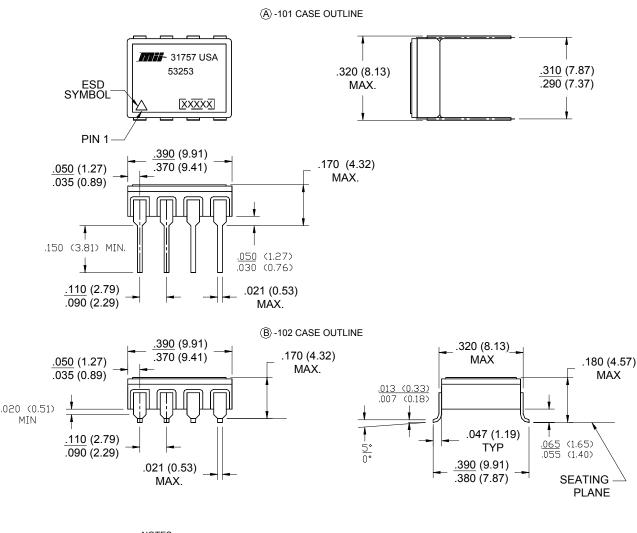


Figure 1 - Terminal Connections

INPUT	OUTPUT
OFF	OFF
ON	ON

Figure 2 - Truth Table



Case Outlines

NOTES:

1. PIN 1 IS INDICATED BY THE ESD TRIANGLE MARKED ON THE LID OF THE PACKAGE.

2. DIMENSIONS ARE IN INCHES, (mm).

METRIC EQUIVALENTS ARE GIVEN FOR GENERAL INFORMATION ONLY.
UNLESS OTHERWISE SPECIFIED, TOLERANCE IS ±.005 (0.13mm).

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